TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (MACH II  $\pi$ -MOS V)

# **TPCS8008-H**

High-Speed Switching Applications Switching Regulator Applications DC-DC Converter Applications

- Low drain-source ON-resistance: RDS (ON) =  $0.48 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 1.8 \text{ S (typ.)}$
- Low leakage current:  $IDSS = 100 \mu A (max) (VDS = 250 V)$
- Enhancement model:  $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

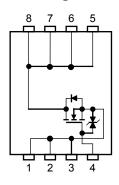
### Absolute Maximum Ratings (Ta = 25°C)

Character	istic	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	250	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	250	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC (Note 1)	I <sub>D</sub>	1.7	Α	
	Pulse (Note 1)	I <sub>DP</sub>	6.8	^	
Drain power dissipatio	n (t = 10 s) (Note 2a)	$P_{D}$	1.5	W	
Drain power dissipatio	n (t = 10 s) (Note 2b)	$P_{D}$	0.6	VV	
Single-pulse avalanch	e energy(Note3)	E <sub>AS</sub>	1.7	mJ	
Avalanche current		I <sub>AR</sub>	1.7	Α	
Repetitive avalanche energy (Note2a, Note 4)		E <sub>AR</sub>	0.15	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature r	ange	T <sub>stg</sub>	-55 to 150	°C	

# Unit: mm | 0.525| | 0.65 | 0.25±0.05 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65 | 0.65

Weight: 0.036 g (typ.)

### **Circuit Configuration**



Note: For Notes 1 to 4, refer to the next page.

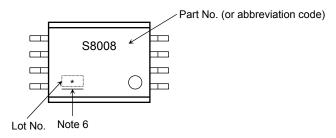
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	83.3	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	208	°C/W

### Marking (Note 5)

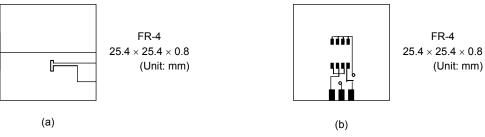


Note 1: The channel temperature should not exceed 150°C during use.

### Note 2:

a) Device mounted on a glass-epoxy board (a)

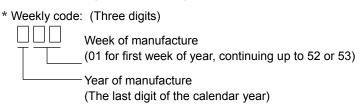
b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD}$  = 50 V,  $T_{ch}$  = 25°C (initial), L = 1.0 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 1.7 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: O on the lower right of the marking indicates Pin 1.



Note 6: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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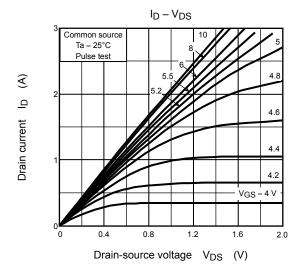
# **Electrical Characteristics (Ta = 25°C)**

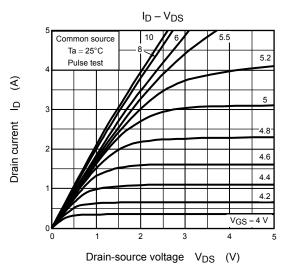
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cutoff curre	rain cutoff current		V <sub>DS</sub> = 250 V, V <sub>GS</sub> = 0 V	_	_	100	μА
Drain-source breakdown voltage  Gate threshold voltage		V <sub>(BR) DSS</sub>	$I_D = 10$ mA, $V_{GS} = 0$ V	250	_	_	V
		V <sub>(BR) DSX</sub>	$I_D = 10 \text{ mA}, V_{GS} = -5 \text{ V}$ 250	250	_	_	
		V <sub>(BR) DSX</sub>	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	200	_	_	
		V <sub>th</sub>	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	2.0	_	4.0	V
Drain-source ON-resistance		R <sub>DS</sub> (ON)	$V_{GS} = 10 \text{ V}, I_D = 0.8 \text{ A}$	_	0.48	0.58	Ω
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_D = 0.8 \text{ A}$	0.8	1.8	_	S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	600	_	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	20	_	pF
Output capacitance		C <sub>oss</sub>		_	220	_	pF
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 10 V	_	35	_	ns
	Turn-on time	t <sub>on</sub>		_	95	_	
	Fall time	t <sub>f</sub>		_	20	_	
	Turn-off time	t <sub>off</sub>	Duty ≤ 1%, t <sub>w</sub> = 10 μs		120		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 200V, V_{GS} = 10 V,$ $I_{D} = 1.7 A$	_	10	_	nC
Gate-source charge		$Q_{gs}$		_	7.5	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>		_	2.5	_	nC
Gate switch charge		Q <sub>sw</sub>		_	3.3	_	nC

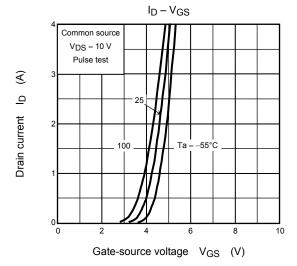
# Source-Drain Ratings and Characteristics (Ta = 25°C)

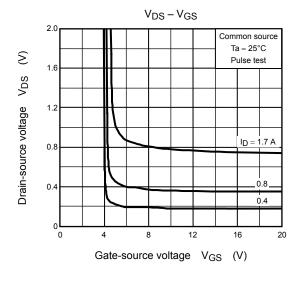
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current (pulse)	(Note 1)	I <sub>DRP</sub>	_	_	_	6.8	Α
Forward voltage (diode)		$V_{DSF}$	$I_{DR} = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$		_	-2.0	V

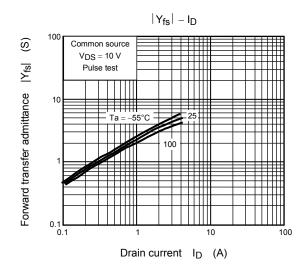
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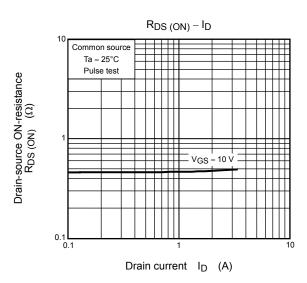




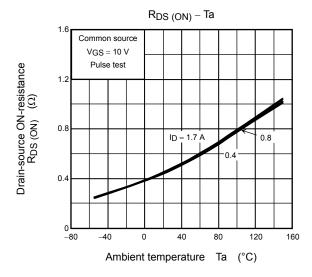


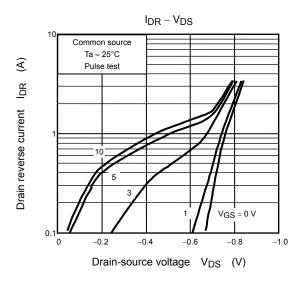


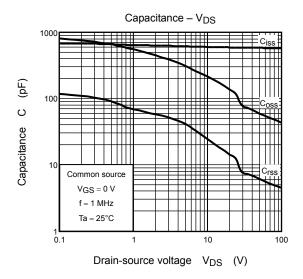


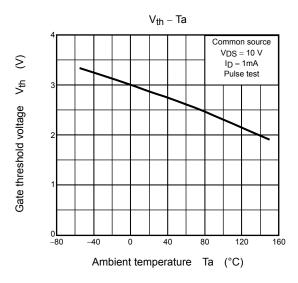


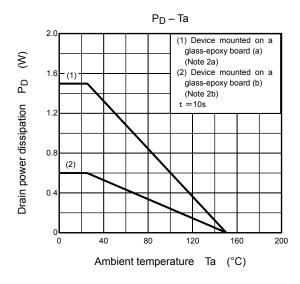
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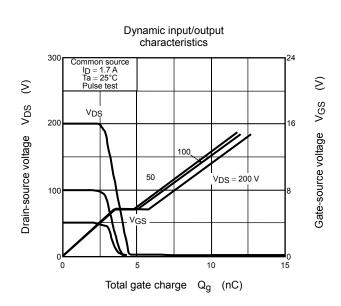


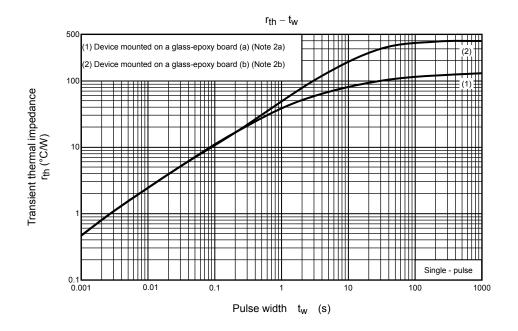


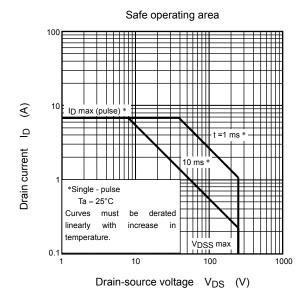












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